





#### 40V PNP MEDIUM POWER HIGH PERFORMANCE TRANSISTOR IN SOT23

#### **Features**

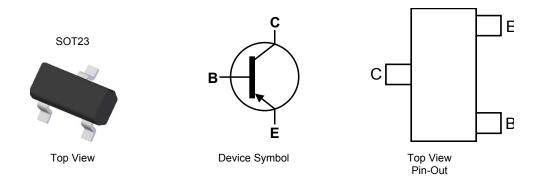
- BV<sub>CFO</sub> > -40V
- I<sub>C</sub> = -1A High Continuous Current
- I<sub>CM</sub> = -2A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -500mV @ -1A</li>
- R<sub>SAT</sub> = 350mΩ for a Low Equivalent On-resistance
- Complementary NPN type: FMMT491A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (approximate)

### **Application**

- Power MOSFET gate driving
- · Low loss power switching



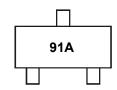
## Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT591ATA	AEC-Q101	91A	7	8	3,000
FMMT591ATC	AEC-Q101	91A	13	8	10,000
FMMT591AQTA	Automotive	91A	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

### **Marking Information**



91A = Product Type Marking Code



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	Icm	-2	Α
Base Current	I <sub>B</sub>	-200	mA
Peak Base Current	Івм	-1	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	$P_{D}$	500	mW
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

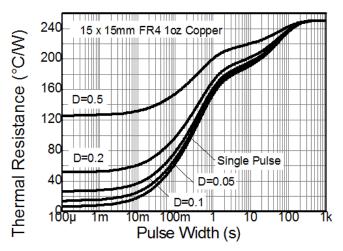
<sup>6.</sup> For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

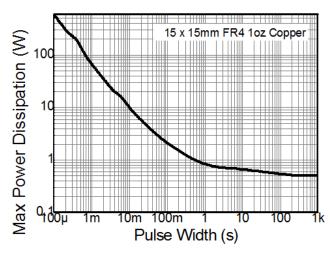
<sup>7.</sup> Thermal resistance from junction to solder-point (at the end of the collector lead).

<sup>8.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



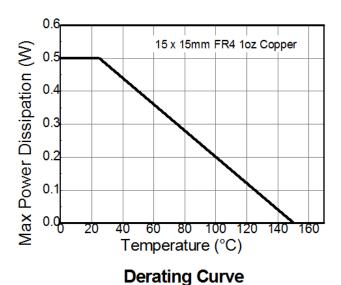
# **Thermal Characteristics and Derating Information**





**Transient Thermal Impedance** 

**Pulse Power Dissipation** 







# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

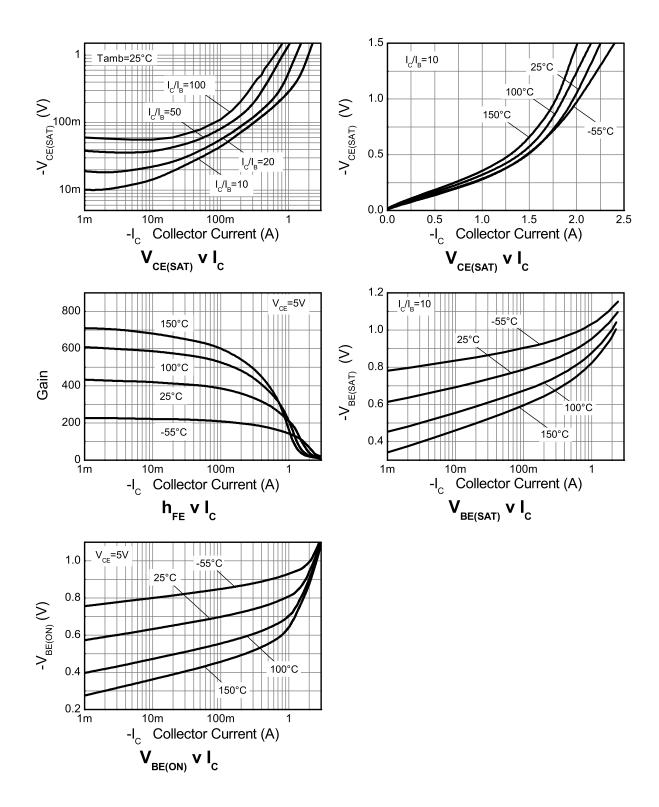
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-40	_	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)		BV <sub>CEO</sub>	-40	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown	Voltage	BV <sub>EBO</sub>	-7	_	_	V	I <sub>E</sub> = -100μA
Collector Cutoff Current		I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -30V
Collector-Emitter Cutoff C	urrent	I <sub>CES</sub>	_	_	-100	nA	V <sub>CES</sub> = -30V
Emitter Cutoff Current		I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5.6V
Collector-Emitter Saturation Voltage (Note 9)		V <sub>CE(sat)</sub>		_	-200 -350 -500	mV	$I_C = -100$ mA, $I_B = -1$ mA $I_C = -500$ mA, $I_B = -20$ mA $I_C = -1$ A, $I_B = -100$ mA
Base-Emitter Saturation V	oltage (Note 9)	V <sub>BE(sat)</sub>	_	_	-1.1	V	$I_C = -1A$ , $I_B = -100mA$
Base-Emitter Turn-On Vo	Itage (Note 9)	V <sub>BE(on)</sub>	_	_	-1.0	V	$I_{C} = -1A, V_{CE} = -5V$
Static Forward Current Transfer Ratio (Note 9)		h <sub>FE</sub>	300 300 250 160 30	_	800 — — —	_	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -100mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -500mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V I <sub>C</sub> = -2A, V <sub>CE</sub> = -5V
Transition Frequency		f <sub>T</sub>	150	00	_	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Output Capacitance		C <sub>obo</sub>		_	10	pF	V <sub>CB</sub> = -10V, f = 1MHz
	Delay Time	t <sub>(d)</sub>		34.9	_		
Switching Time	Rise Time	t <sub>(r)</sub>		19.2	_		$V_{CC} = -10V, I_{C} = -500mA,$
Switching Time	Storage Time	t <sub>(s)</sub>	_	249	_	ns	$I_{B1} = -I_{B2} = -25 \text{mA}$
	Fall Time	t <sub>(f)</sub>	_	62	_		

Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ 





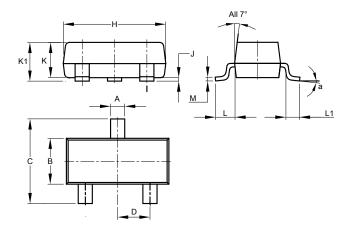
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# **Package Outline Dimensions**

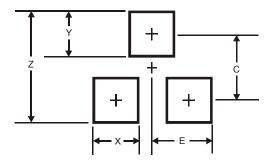
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	8°					
All	All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
С	2.0
E	1.35





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